

DATA SHEET

For a complete data sheet, please also download:

- The IC04 LOCMOS HE4000B Logic Family Specifications HEF, HEC
- The IC04 LOCMOS HE4000B Logic Package Outlines/Information HEF, HEC

HEF4081B **gates** Quadruple 2-input AND gate

Product specification
File under Integrated Circuits, IC04

January 1995

Quadruple 2-input AND gate

HEF4081B
gates

QUADRUPLE 2-INPUT AND GATE

The HEF4081B provides the positive quadruple 2-input AND function. The outputs are fully buffered for highest noise immunity and pattern insensitivity of output impedance.

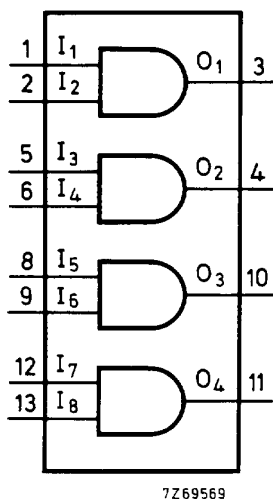


Fig.1 Functional diagram.

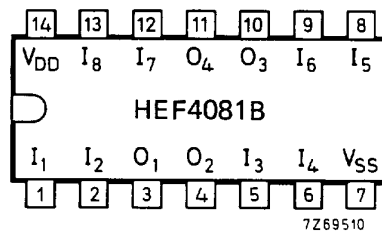


Fig.2 Pinning diagram.

- HEF4081BP(N): 14-lead DIL; plastic (SOT27-1)
- HEF4081BD(F): 14-lead DIL; ceramic (cerdip) (SOT73)
- HEF4081BT(D): 14-lead SO; plastic (SOT108-1)
- (): Package Designator North America

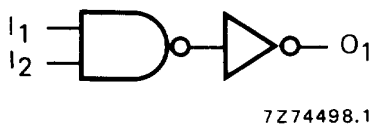


Fig.3 Logic diagram (one gate).

FAMILY DATA
IDD LIMITS category GATES } see Family Specifications

Quadruple 2-input AND gate

HEF4081B
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A.C. CHARACTERISTICS

$V_{SS} = 0 \text{ V}$; $T_{amb} = 25 \text{ }^\circ\text{C}$; $C_L = 50 \text{ pF}$; input transition times $\leq 20 \text{ ns}$

	V_{DD} V	symbol	typ.	max.		typical extrapolation formula	
Propagation delays $I_n \rightarrow O_n$ HIGH to LOW	5	tPHL	55	110	ns	$28 \text{ ns} + (0,55 \text{ ns/pF}) C_L$	
	10		25	50	ns	$14 \text{ ns} + (0,23 \text{ ns/pF}) C_L$	
	15		20	40	ns	$12 \text{ ns} + (0,16 \text{ ns/pF}) C_L$	
	LOW to HIGH	5	tPLH	45	90	ns	$18 \text{ ns} + (0,55 \text{ ns/pF}) C_L$
		10		20	40	ns	$9 \text{ ns} + (0,23 \text{ ns/pF}) C_L$
		15		15	30	ns	$7 \text{ ns} + (0,16 \text{ ns/pF}) C_L$
Output transition times	5	tTHL	60	120	ns	$10 \text{ ns} + (1,0 \text{ ns/pF}) C_L$	
	10		30	60	ns	$9 \text{ ns} + (0,42 \text{ ns/pF}) C_L$	
	15		20	40	ns	$6 \text{ ns} + (0,28 \text{ ns/pF}) C_L$	
	LOW to HIGH	5	tTLH	60	120	ns	$10 \text{ ns} + (1,0 \text{ ns/pF}) C_L$
		10		30	60	ns	$9 \text{ ns} + (0,42 \text{ ns/pF}) C_L$
		15		20	40	ns	$6 \text{ ns} + (0,28 \text{ ns/pF}) C_L$

	V_{DD} V	typical formula for P (μW)	where f_i = input freq. (MHz) f_o = output freq. (MHz) C_L = load capacitance (pF) $\Sigma(f_o C_L)$ = sum of outputs V_{DD} = supply voltage (V)
Dynamic power dissipation per package (P)	5	$450 f_i + \Sigma(f_o C_L) \times V_{DD}^2$	
	10	$2900 f_i + \Sigma(f_o C_L) \times V_{DD}^2$	
	15	$11700 f_i + \Sigma(f_o C_L) \times V_{DD}^2$	